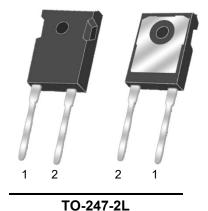




Schoktty Barrier Diode

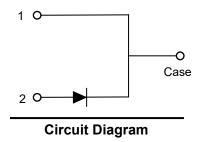
Feature

- ➤ Low conduction loss due to low V_F
- > Extremely low switching loss by tiny Q_C
- ➤ Negligible reverse recovery
- > Positive Temperature Coefficient
- ➤ Pb-free / RoHS compliant
- > Highly rugged due to better surge current
- ➤ High-reliability



Applications

- > Solar inverters
- > Uninterruptable power supplies
- Motor drives
- > Power Factor Correction



Absolute maximum rating@25°C

| Parameter | | | Value | Units |
|-----------------------------------------|-----------------------------------------------------------|------------------|----------|------------------|
| Repetitive Peak Reverse Voltage | | V_{RRM} | 650 | ٧ |
| Surge Peak Reverse Voltage | | V _{RSM} | 650 | V |
| DC Peak Reverse Voltage | | V _R | 650 | V |
| Continuous Forward Current | T _c =25°C | I _F | 60 | А |
| | T _c =155°C | | 15 | |
| Non-repetitive Forward Surge Current | T _c =25°C,t _p =10ms,Half Sine Pulse | I _{FSM} | 128 | Α |
| i²t Value | $T_c=25$ °C, $t_p=10$ ms | ∫i² dt | 72 | A ² s |
| Power Dissipation | T _c =25°C | Б | 217 | W |
| | T _c =110°C | P _{tot} | 94 | |
| Operating Junction Range | | T _J | -55~+175 | °C |
| Storage Temperature Range | | T _{STG} | -55~+175 | °C |

Electrical characteristics per line@25°C (unless otherwise specified)

| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units | |
|---------------------------|----------------|------------------------------------------------------------------|------|------|------|-------|--|
| Forward Voltage | V _F | I _F = 15A, Τ _J =25°C | - | 1.28 | 1.55 | V | |
| | | I _F = 15A, T _J =135°C | - | 1.31 | 1.69 | | |
| | | I _F = 15A, T _J =175°C | - | 1.39 | 1.89 | | |
| Reverse Current | I _R | V _R = 650V, T _J =25°C | - | 1 | 50 | | |
| | | V _R = 650V, T _J =175°C | - | 18 | 200 | μA | |
| Total Capacitive Charge | Q _C | $V_R = 400V, T_j = 25^{\circ}C,$ $Q_C = \int_0^{V_R} C(V) dV$ | - | 56 | - | nC | |
| | | $V_R = 0V, f = 1MHz$ | - | 826 | - | | |
| Total Capacitance | С | V _R = 300V,f = 1MHz | - | 91 | - | pF | |
| | | V _R = 600V,f = 1MHz | - | 79 | - | | |
| Capacitance stored energy | E _C | V _R = 400V | - | 8.5 | - | μJ | |

Thermal Characteristics

| Parameter | Symbol | Min. | Тур. | Max. | Units |
|---------------------------------------|-----------------|------|------|------|-------|
| Thermal Resistance (Junction to case) | $R_{\theta JC}$ | - | 0.69 | - | °C/W |

Typical Characteristics

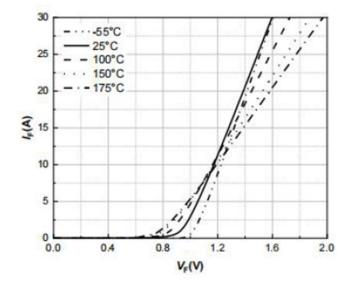


Fig.1 Forward Characteristics

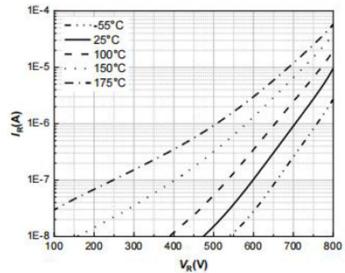
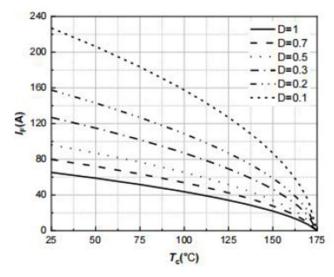


Fig.2 Reverse Characteristics

Schoktty Barrier Diode

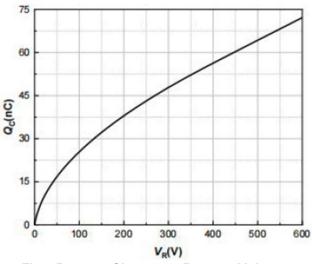
PSICS2TAF650V15N



1000 800 600 400 200 0.1 1 10 100 1000 V_R(V)

Fig.3 Current Derating

Fig.4 Capacitance Charge vs. Reverse Voltage



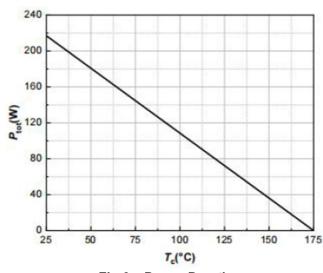
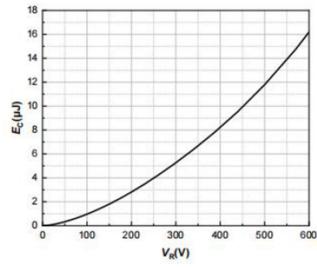


Fig.5 Reverse Charge vs. Reverse Voltage

Fig.6 Power Derating



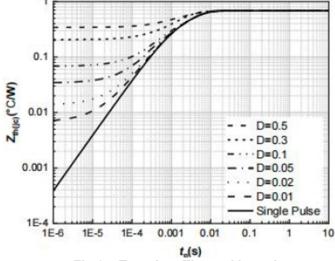
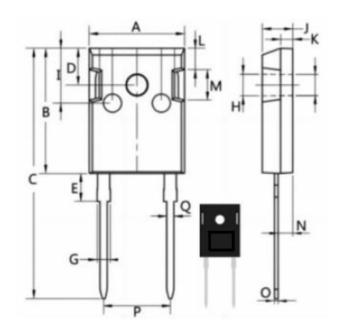


Fig.7 Capacitance Stored Energy

Fig.8 Transient Thermal Impedance

Product dimension (TO-247-2L)



| Dim | Millimeters | | |
|-----|-------------|-------|--|
| Dim | Min | Max | |
| А | 15.5 | 15.7 | |
| В | 20.35 | 20.55 | |
| С | 20.45 | 20.85 | |
| D | 5.89 | 6.17 | |
| E | 4.14 | 4.45 | |
| G | 1.13 | 1.19 | |
| Н | 4.45 | 4.55 | |
| I | 8.15 | 8.60 | |
| J | 4.95 | 5.05 | |
| K | 1.96 | 1.99 | |
| L | 3.24 | 3.72 | |
| M | 4.625 | 4.725 | |
| N | 2.35 | 2.41 | |
| 0 | 0.592 | 0.608 | |
| Р | 1.13 | 1.18 | |

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